## MULTIFERROICS AND MAGNETOELECTRIC EFFECTS



#### Dr. Silvia Picozzi

Consiglio Nazionale delle Ricerche, CNR-SPIN, UOS L'Aquila 67100 L'Aquila, Italy

#### Project "BISMUTH":





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# FERROELECTRICITY: BASICS

What is a ferroelectric? Why is ferroelectric? Which are the most famous FE materials?





#### FERROELECTRICITY: BASICS

•Ferroelectrics: polar materials, in which a spontaneous electric polarization can be switched via an external electric field (P: primary order parameter in the phase transition)



#### Order-disorder" vs "displacive



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#### PROPER DISPLACIVE FERROELECTRICITY



•BaTiO<sub>3</sub>: Up or down displacement of B-site cation

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#### **PROPER DISPLACIVE FERROELECTRICITY**







### FERROELECTRICITY: BASICS

- •The electric polarization (P) vs field (E) draws a **hysteretic curve** (P–E loop)
- •The critical electric field for reversing P is called "**coercive field**".
- The electric "**bistability**" can be used, i.e, for non-volatile memory elements.
- Ferroelectrics usually have a Curie temperature  $T_c$  for a paraelectric-to-ferroelectric phase transition.







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Materials	Transition		Dielectric constant	
	tempera	ature (K)		
	T <sub>c</sub>	T <sub>c</sub> D	κ <sub>ят</sub>	Kmsa
norganic compounds	-	-		
NaNO <sub>2</sub>	437			$4 \times 10^{3}$
BaTiO3	381		$5 \times 10^{3}$	10⁴
PbTiO₃	763		210	$9 \times 10^{3}$
SbSl	293			6 × 10⁴
KH₂PO₄ (KDP)	123	213	30	2×10⁴
Organic–inorganic con				
HdabcoReO₄	374		6	22
TGS	323	333	45	2 × 10 <sup>3</sup>
ISCC	127		5	80
Rochelle salt	297	308		$4 \times 10^3$
Materials		<i>P</i> <sub>s</sub> (μC cm <sup>-2</sup> );	E <sub>c</sub> (kV cm <sup>-1</sup> )	
		temperature		
NaNO		10: 140 K		5
NaNO2 RaTi∩		26: RT		10
Dario <sub>3</sub> Dhtin		75: RT		7 C Hariyahi
shsi		20: 270 K		
KH_PO. (KDP)		5.0		
Organic-inorganic con				Y. IOKUľa,
HdahcoReO.		16: RT*		>30 Nature
IGS		3.8; 220 K		0.9 Mater.
ISCC		0.27; 80 K		<b>3 7</b> , 357
Rochelle salt		0.25; 276 K		0.2 (2008)





# COMPLEX OXIDES: BASICS

What is a complex oxide? Why are they interesting? Why are they useful? How to model them?





### WHAT ARE CORRELATED OXIDES?

Systems with correlated electrons: one electron explicitely influences the others



### CHARGE, SPIN, ORBITALS AND ALL THAT JAZZ...

Complex oxides as exotic systems





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#### **COMPARISON WITH SEMICONDUCTORS**

#### **Conventional semiconductors**

#### Physics:

large overlap of s/p orbitals
gives extended wavefunctions
no intrinsic magnetism or other
correlations

#### Technology:

— Quality: high! can be fabricated into complex structures

- Understanding:

Semiconductor modeling is straightforward

— Tunability: control charge with modest doping/ E fields

#### **Complex oxides**

#### <u>Physics:</u>

localization of 3d/2p orbitals
gives strong Coulomb interact.
diverse magnetic and other
correlations

#### Technology:

Quality: materials chemistry challenging; fabrication less developed
Understanding: strong correlations challenging to theoretical tools
Tunability: high! due to competing ordered states





### COMPLEX OXIDES: TUNABILITY VS COMPLEXITY

Many "couplings":

electron-lattice

spin-electron-lattice



Physics phenomena:

ferroelectricity high-Tc superconductivity

multiferroism magnetoelectricity magnetoresistance spintronics magnetic frustration

Spin/orbital/lattice couplings with similar energy scales: small changes (surfaces, interfaces, defects, external perturbations) can alter the balance between competing large energy interactions and dramatically change the ground state >> **TUNABILITY!** 





### COMPLEX OXIDES: TUNABILITY VS COMPLEXITY

Many "couplings":

electron-lattice

spin-electron-lattice





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#### **SEMICONDUCTORS VS OXIDES**

#### APPLIED PHYSICS

# **Oxide Electronics Emerge**

Arthur P. Ramirez

Microelectronics are built from materials whose electrons interact strongly and can exhibit properties as a group that are not seen in any one particle.

www.sciencemag.org SCIENCE VOL 315 9 MARCH 2007

Vastly richer physics suggests entirely new functionalities !

1377

#### **OXIDES CLASSIFICATION**





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# FIRST-PRINCIPLES CALCULATIONS: BASICS

Density functional theory Main theorem Why are they useful for multiferroics? Where do they fail?





## WHAT ARE FIRST-PRINCIPLES USEFUL FOR?

- **MODELLING AND UNDERSTANDING**: Sort out microscopic mechanisms and physical models.
- **COMPUTER-EXPT:** Ask "what if" questions.
- MATERIALS DESIGN: Screen ideas for new/modified materials
- THEORY VS EXPERIMENT: Interpret experimental data, compare spectra, etc



• **ERRORS...** Analyze failures. Ask: Are the approximations used appropriate? Can the models address the essential complexity of the system? Is the theory appropriate for the key properties?





The basic quantity is not the many-body wave-function but the **electronic density n(r)** 

- Hohenberg-Kohn theorem (1964)
- All properties of the many-body system are determined by the ground state density n<sub>Gs</sub>(r)
- Each property is a <u>functional</u> of the ground state density n<sub>GS</sub>(r) which is written as f [n<sub>GS</sub>]
- In particular, the energy is:



 $E[n(\mathbf{r})] = F[n(\mathbf{r})] + \int V_{ext} n(\mathbf{r}) d\mathbf{r} = \mathbf{T}_{e} + \mathbf{U}_{ee} + \int V_{ext} n(\mathbf{r}) d\mathbf{r} \ge E[n_{GS}(\mathbf{r})]$ 

and satisfies a variational principle





#### •Kohn-Sham equations (1965)





Auxiliary system: Non-interacting fictitious particles + effective potential

Interacting electrons + External potential

The ground state density is required to be the same as the exact density  $n_{0}(\mathbf{r}) = \sum \sum |\psi^{\sigma}(\mathbf{r})|^{2}$ 

$$n_0(\mathbf{r}) = \sum_{\sigma} \sum_{i=1} |\psi_i^{\sigma}(\mathbf{r})|^2,$$

Minimization of E leads to one-particle Kohn-Sham equations for independent particles (soluble):

$$[-1/2 \nabla^2 + V_{eff}[n(r)]] \psi_i = \varepsilon_i \psi_i$$



#### •Kohn-Sham equations (1965)

 $\{-1/2 \nabla^2 + V_{eff}[n(r)]\} \psi_i = \varepsilon_i \psi_i$ 

where:  $V_{eff}[n(r)] = V_{ext}(r) + V_{H}(r) + V_{xc}[n(r)]$ 

•V<sub>ext</sub>(r) is the nuclei (external) potential







- Approximations to the functional  $E_{xc}$ 
  - Local Density Approximation LDA
    - Assume the functional is the same as a model problem
      - the homogeneous electron gas
    - E<sub>xc</sub> has been calculated as a function of density using quantum Monte Carlo methods (Ceperley & Alder)
  - Gradient approximations GGA
     Various theoretical improvements for electron density that varies in space





## **OPERATIVELY**...

- Structure, types of atoms, guess for input charge
- Find the potential
- Solve KS Eqs.
- New Density and Potential
- Self-consistent?
- Output:
  - Total energy, force, ....
  - Eigenvalues



#### Self-Consistent Kohn-Sham Equations

Initial Guess $n^{\uparrow}(r), n^{\downarrow}(r)$ 

### WHAT CAN WE GET OUT OF THE COMPUTER?

Capabilities, formalism	Predicted quantities		
Spin-DFT	Electronic structure (DOS, bands,), magnetism (moments, GS spin configuration,)		
Hellman-Feynman	FE displacements		

ā

#### THE GOOD AND THE BAD OF DFT FOR COMPLEX OXIDES

BUT... V<sub>xc</sub>(r) is approximated "Standard" local density approximation (LDA) designed for a homogeneous electron gas .... How to approach strong correlations ?

#### • Beyond-LDA methods:

- LDA+U attempts to incorporate Coulomb repulsions (U)
- Hybrid functionals (mix of "exact-exchange" and LDA)

#### • Hamiltonian modelling:

Extract essential interaction parameters from LDA and construct a model , but also provide a fully independent approach to test the results...





## **MULTIFERROICS: BASICS**

What are they? Why are they useful? Are they many or few? Lone-pair MFs Composite MFs







## PROPAGANDA

 Number of papers listed in ISI Web of Science
 with keyword "multiferroic"

The Science magazine has declared MFs as an "area to watch" in 2008

Multiferroics. Relatives of ceramic oxide superconductors, the compounds called multiferroics form a group in which single materials display multiple electronic, magnetic, and structural behaviors. Physicists recently used electric fields to manipulate magnetic domains in a multiferroic. Now, they are racing to better control this switching and shape the materials into novel computer chip devices. Success could pave the way for chips that combine the logic functions normally handled by semiconductors with the memory functions now carried out by magnetic materials.



N. A. Spaldin, R. Ramesh and S. W. Cheong





"For groundbreaking contributions in theory and experiment that have advanced the understanding and utility of multiferroic oxides"





### MAGNETOELECTRICS MULTIFERROICS: WHAT ARE THEY?



N.A. Spaldin and M. Fiebig, Science **309**, 391 (2005)

 ➢ Ferroic: P, M or € are spontaneously formed to produce ferroelectricity, ferromagnetism or ferroelasticity
 ➢ Multiferroic: coexistence of at least two kinds of long-range ordering





### MAGNETOELECTRICS MULTIFERROICS: WHY ARE THEY INTERESTING?





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### (MULTI-) FERROICS: SYMMETRY PROPERTIES



W. Eerenstein, N. D. Mathur and J. F. Scott, N ature 442, 759 (2006)





#### **CRITERIA FOR MAGNETISM AND FERROELECTRICITY**

- •Uncompensated spins form magnetic moments
- Exchange interaction results from virtual hopping of electrons between ions
  - In order to stabilize ferro- or ferri- or antiferromagnetism one needs **partially filled d-shells**!
- Ferroelectricity requires "do-ness"
  Ferromagnetism (or FiM- or AFM) requires partially filled d-electrons



WAY OUT:



Put FE-active ion on A-site Put magnetic ion on B-site



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### **CLASSIFICATION OF MULTIFERROICS**



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### **CLASSIFICATION OF MULTIFERROICS**





#### STRAIN-MEDIATED MAGNETOELECTRIC COUPLING



Nano-columns

•Strain coupling requires contact between a piezomagnetic (or magnetostrictive) and a piezoelectric (or electrostrictive) material. •For nanopillars of  $CoFe_2O_4$  in a BaTiO<sub>3</sub> matrix: observed change in magnetization (around 5%) of the  $CoFe_2O_4$  pillars at the ferroelectric Curie temperature. •For nanopillars of  $CoFe_2O_4$  in a BiFeO<sub>3</sub> matrix: reported electricallyinduced magnetization reversal





Conventional magnetic tunnel junctions (MTJ):

- information stored by the magnetic configuration of the electrodes
- the barrier a diamagnetic dielectric is a «passive» element

TUNNEL JUNCTIONS WITH FERROELECTRIC AND/OR FERROMAGNETIC BARRIER

Ferroic insulators bring additional degrees of freedom to MTJs because the barrier can store info

Ferro(i)magnetic barriers : spin-filteringFerroelectric barriers

Even more, junctions with multiferroic barrier can be used to : •Store more-than-binary information

FM metal

Insulator

FM metal

•Control the magnetic state by an electric field through the magneto-electric coupling







M. Gajek et al., Nature Mat. (2007)



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TUNNEL JUNCTIONS WITH FERROELECTRIC AND/OR FERROMAGNETIC BARRIER

Figure 1 Schematic representation of the tunnel barrier potential profiles and tunnel currents for a ferromagnetic and a ferroelectric barrier, a, Schematic diagram of the spin-dependent tunnelling for parallel (left) or antiparallel (right) configurations of the LBMO and LSMO magnetizations, considering a half-metallic LSMO electrode with only spin-up states at the Fermi level E<sub>F</sub>. For simplicity, we assume a non-ferroelectric LBMO barrier.  $\Phi_0$  is the barrier in the absence of ferromagnetism and  $\Delta \Phi_{rr}$  is the exchange splitting. Spin-up is represented in red and spin-down in blue. In the parallel case, spin-up electrons tunnelling from LSMO experience a small barrier height ( $\Phi_0 = \Delta \Phi_{ex}/2$ ), which results in a large current density (J, shown by a red arrow) and a low resistance. In the antiparallel case, these electrons tunnel through a larger barrier height ( $\Phi_1 + \Delta \Phi_{ex}/2$ ), which results in a low current and a large resistance. b, Schematic diagram of the potential profile seen by the tunnelling electrons for the two directions of the barrier electric polarization, according to the model in ref. 13 (assuming a non-magnetic barrier).  $\Phi_0$  is the barrier in the absence of polarization.  $\Phi_+$  and  $\Phi_-$  are the average barrier heights seen by the carriers when P points towards LSMO and Au, respectively. The black arrows indicate the direction of the ferroelectric polarization in the barrier. The purple arrows indicate the current density.

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#### **CLASSIFICATION OF MULTIFERROICS**



#### "LONE-PAIR" ACTIVE MULTIFERROICS

• Ferroelectricity from the "stereochemically active lone pair" on Bi<sup>3+</sup> (cf ammonia, NH<sub>3</sub>)

• Magnetism from a 3d transition metal (Mn<sup>3+</sup> or Fe<sup>3+</sup>)



**BiMnO<sub>3</sub>**: Ferromagnetic + Polar instability from Bi lone pairs Anti-polar? (C2/c) Bi Bi Bi P. Baettig, R. Seshadriand N. A. Spaldin, "Anti-polarity in ideal BiMnO3", JACS 129, 9854-9855 (2007).

**BiFeO<sub>3</sub>**: Ferroelectric,  $P = 90 \mu C/cm^2 +$ Polar instability from Bi Ione pairs Anti-ferromagnetic (weak FM)

"Epitaxial BiFeO3 multiferroic thin film heterostructures", Wang, Spaldin, Ramesh et al., Science 299, 1719 (2003)







#### THE "HOLY GRAIL": BiFeO<sub>3</sub>

- A room-temperature multiferroic: FE and AFM (or weak FM)
- Good agreement between theory and experiments for P
- (~100  $\mu$ C/cm<sup>2</sup> along [111] or, equivalently, ~60  $\mu$ C/cm<sup>2</sup> along [001])





# **BiFeO3: MAGNETISM**

• Bulk: G-type AFM and cycloidal modulation ( $\lambda$ ~640 nm) • Thin films: the modulation disappears but a weak FM arises

> Fe AFM moments are canted by up to ~1° due to Dzyaloshinskii-Moriya interaction  $E_{\rm DM} = -\frac{1}{2}\vec{D} \cdot (\vec{M}_{\rm Fe1} \times \vec{M}_{\rm Fe2}) = -\vec{D} \cdot (\vec{L} \times \vec{M})$  $\vec{M} = \vec{M}_{\rm Fe1} + \vec{M}_{\rm Fe2}$ ;  $\vec{L} = \vec{M}_{\rm Fe1} - \vec{M}_{\rm Fe2}$





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## **BiFeO3: MAGNETISM**

Is the canting coupled to polarization ?

Can I switch the weak moment by E-field?



No! Two different modes in BFO:

Polar displacements along [111]
 Octahedral counter-rotations

.... and DM is related to Oxygen octahedral rotations





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# **HYBRID FUNCTIONALS**

Linear combination of Hartree-Fock-exchange and of DFT (parametrized) exchange:

$$E_{xc}^{Hybrid} = a E_{x}^{HF} + (1-a) E_{x}^{PBE} + E_{c}^{HPBE}$$

The parameter a can be theoretically derived: a = 1/4 for PBEO

$$E_{xc}^{Hybrid} = 1/4 E_{x}^{HF} + 3/4 E_{x}^{PBE} + E_{c}^{HPBE}$$

Heyd-Scuseria-Erzenhof (HSE) Functional\*: mixing only of the short-range (SR) component of the HF exchange:

 $E_{xc}^{HSE} = 1/4 E_x^{HF,SR}(\mu) + 3/4 E_x^{PBE,SR}(\mu) + E_x^{PBE,LR} + E_c^{HPBE}$ 

\* J. Heyd et al., J. Chem. Phys. **118**, 8207 (2003).







# IMPROPER FERROELECTRICITY IN MAGNETS

What do we mean by "improper ferroelectricity"? Concepts: how to break inversion symmetry via spin- or charge-ordering Frustration

Examples: manganites and metal-organic frameworks





# BREAKING INVERSION SYMMETRY IN MAGNETS



• "Proper"

- Ionic displac. break inversion symmetry (IS)
  "Covalency"-driven
- "Improper"
  Electron degrees of freedom break IS
- "Correlation"-driven





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Non-(

Main advantages over proper multiferroics:

displacements/switching involve electrons rather than ions
 ⇒ switching should be much faster
 ⇒ better as for "fatigue"





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#### HOW MAGNETIC ORDERING CAN BREAK INV. SYM.?



T.Kimura et al., Nature 425, 55 (03); S.W.Cheong and M.Mostovoy, Nature Mater. 6, 13 (07)

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#### **DZYALOSHINSKII-MORIYA VS HEISENBERG**

 $p \propto r_{ij} \propto (S_1 \times S_2)$  Vector coupling: Requires non-collinear spins  $p?(S_1 \cdot S_2)$  Scalar coupling: Works with collinear spins





#### Superexchange striction



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Direct exchange striction

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## **DZYALOSHINSKII-MORIYA VS HEISENBERG**

 $p \propto r_{ii} \propto (S_1 \times S_2)$  Vector coupling: Requires non-collinear spins

 $p?(S_1 \cdot S_2)$ 

Scalar coupling: Works with collinear spins





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#### HOW CHARGE ORDERING CAN BREAK INV. SYM.?

Neutral chain

"Pure" charge-ordering

Structural dimerization

Combination Intermediate Bond- and site centered CO



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Inversion center: no P



Through center of symmetry: cancellation ==>> P = 0!

Absence of inversion center: P finite! ... but these are just "sketches"... In practice we have to find materials where these "local" dipoles are periodically repeated

 $\Rightarrow$  polar space groups





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# CLASSIFICATION OF IMPROPER MULTIFERROICS





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## WHAT ABOUT THE SIZE OF P?





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#### **FRUSTRATION IN MAGNETS**

#### Spins on a triangular lattice with AFM coupling



#### =>> Complex non-collinear spin configurations !!



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#### **FRUSTRATION IN MAGNETS**





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#### **FRUSTRATION IN MAGNETS**

Frustrated spin chains with the nearest-neighbour FM and next-neighbour AFM interactions J and J' .







# **ROLE OF ORBITAL ORDERING**

(a)

MAGNETITE

(b)

B12

S//c

s o

It does not break inversion symmetry by itself, but it is a needed ingredient in many cases !

z = 8/8

z = 7/8 B12

 $(Fe^{2+})$ 

z = 6/8

= 5/8

= 4/8

**S**//**b** 

S >

B14 (Fe3+)





# TWO "OLD" EXAMPLES OF MULTIFERROICS

PRL 99, 227201 (2007)

PHYSICAL REVIEW LETTERS

week ending 30 NOVEMBER 2007

#### Dual Nature of Improper Ferroelectricity in a Magnetoelectric Multiferroic

S. Picozzi,<sup>1</sup> K. Yamauchi,<sup>1</sup> B. Sanyal,<sup>2</sup> I. A. Sergienko,<sup>3,4</sup> and E. Dagotto<sup>3,4</sup>

<sup>1</sup>Consiglio Nazionale delle Ricerche–Istituto Nazionale di Fisica della Materia (CNR-INFM), CASTI Regional Laboratory, 67010 L'Aquila, Italy

<sup>2</sup>Theoretical Magnetism Group, Department of Physics, Uppsala University, Box-530, SE-75121, Uppsala, Sweden <sup>3</sup>Materials Science & Technology Division, Oak Ridge National Laboratory, Oak Ridge, Tennessee 37831, USA <sup>4</sup>Department of Physics & Astronomy, The University of Tennessee, Knoxville, Tennessee 37996, USA (Received 8 May 2007; published 26 November 2007)







DOI: 10.1002/anie.201101405

#### Electric Control of Magnetization and Interplay between Orbital Ordering and Ferroelectricity in a Multiferroic Metal–Organic Framework\*\*

Alessandro Stroppa,\* Prashant Jain,\* Paolo Barone, Martijn Marsman, Juan Manuel Perez-Mato, Anthony K. Cheetham, Harold W. Kroto, and Silvia Picozzi



# E-TYPE MANGANITES: ELECTRONIC AND IONIC FERROELECTRICITY

•In collaboration with:

K. Yamauchi (now at Osaka)









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# WHY THE AFM-E SHOULD BE FERROELECTRIC ?

• "Electronic" mechanisms





• e<sub>a</sub> Orbital Ordering • Oxygen inequivalency







# WHY THE AFM-E SHOULD BE FERROELECTRIC ?

• "Switching" mechanisms: change direction of some spins



• e<sub>a</sub> Orbital Ordering









# WHY THE AFM-E SHOULD BE FERROELECTRIC ?

• "Structural" contributions: Magnetostriction







# ORTHO-HoMnO3 AS A MAGNETICALLY DRIVEN FERROELECTRIC

- First ab-initio calculation of P driven by AFM\*
- P is ~few μC/cm<sup>2</sup> (highest among magnetic improper ferroelectrics)
- FE switching path via spin-rotations
- Dual nature of P in real compounds: ionic displacements and electronic/magnetic effects are both important
- \* S. Picozzi, K. Yamauchi, B. Sanyal, I. Sergienko, E. Dagotto, PRL 99, 227201 (2007)









# ORGANICS & HYBRIDS

•In collaboration with:

A. Stroppa (CNR-SPIN) S. Horiuchi, Y. Tokura (Univ. Tokyo) S. Kumar, J. Van den Brink (IFW Dresden) A.K. Cheetham (Univ. Cambridge) P. Jain, H. W.Kroto (Florida State Univ)





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#### **PROTON TRANFER: EFFICIENT SOURCE OF P**

Vol 463 11 February 2010 doi:10.1038/nature08731

nature



# Above-room-temperature ferroelectricity in a single-component molecular crystal

Sachio Horiuchi<sup>1</sup>, Yusuke Tokunaga<sup>2</sup>, Gianluca Giovannetti<sup>3,4</sup>, Silvia Picozzi<sup>3</sup>, Hirotake Itoh<sup>2</sup>, Ryo Shimano<sup>2,5</sup>, Reiji Kumai<sup>1</sup> & Yoshinori Tokura<sup>1,2,6</sup>



#### TTF-CA: SPIN-PEIERLS AS A SOURCE OF P ?





G. Giovannetti et al., PRL 103 26401 (2009)



#### MATERIALS SCIENCE

#### There's Room in the Middle

Anthony K. Cheetham and C. N. R. Rao

Dense inorganic-organic hybrid materials offer opportunities for creating unusual properties or combinations of properties.

5 OCTOBER 2007 VOL 318 SCIENCE www.sciencemag.org

Crystalline hybrid materials like **Metal Organic Frameworks (MOFs)** are very attractive materials for gas storage, drug delivery, catalysis, optics, and magnetism



Multiferroic Behavior Associated with an Order–Disorder Hydrogen Bonding Transition in Metal–Organic Frameworks (MOFs) with the Perovskite ABX<sub>3</sub> Architecture J. AM. CHEM. SOC. 2009, 131, 13625–13627

Prashant Jain,<sup>†,‡,§</sup> Vasanth Ramachandran,<sup>†</sup> Ronald J. Clark,<sup>†</sup> Hai Dong Zhou,<sup>§</sup> Brian H. Toby,<sup>II</sup> Naresh S. Dalal,<sup>†,§</sup> Harold W. Kroto,<sup>†</sup> and Anthony K. Cheetham<sup>\*,‡</sup>



# Cu-MOF (ABX<sub>3</sub>, K<sup>+</sup>CuF<sup>-1</sup><sub>3</sub> LIKE)



Cu octahedra connected by **HCOO**<sup>-</sup> groups (ligands)

Cu<sup>+2</sup> Jahn-Teller ion

Antiferrodistortive order in the ab plane





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# Cu-MOF: FERROELECTRICITY



 $\lambda$  amplitude of the polar distortion:

 $\lambda$ =0 paraelectric state (P=0);  $\lambda$ =+/- 1 ferroelectric (FE) state (P=0.37  $\mu$ C/cm2).

NB.: The AFD order is non-polar in usual inorganic compound (like KCuF3)

 $\phi$  = amplitude of the antiferrodistortive (AFD) order

In Cu-MOF AFD and FE are clearly correlated!





# **Cu-MOF: MAGNETOELECTRICITY**

Symmetry analysis: Coupling of the type M<sub>a</sub>P<sub>c</sub>L<sub>c</sub> ⇒ Weak-FM component Is allowed in Cu-MOF and coupled to the Ferroelectric order!



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- 6. Y. Tokura, Science **312**, 1481 (2006)
- 7. J.F. Scott, Science **315**, 954 (2007)
- 8. R. Ramesh, N.A. Spaldin, Nature Mater. 6, 21 (2007)




